



# Standard Specification for Semiconductor Device Passivation Opening Layouts<sup>1</sup>

This standard is issued under the fixed designation F 1211; the number immediately following the designation indicates the year of original adoption or, in the case of revision, the year of last revision. A number in parentheses indicates the year of last reapproval. A superscript epsilon ( $\epsilon$ ) indicates an editorial change since the last revision or reapproval.

## 1. Scope

1.1 This specification covers standard semiconductor device passivation opening layouts for various tape automated bonding interconnection technologies.

1.2 This specification established the nominal passivation opening dimensions, nominal passivation, opening spacing, nominal corner passivation opening offset, minimum scribe guard and minimum die size for the most common input/output counts within each technology.

1.3 This specification is extendable to other interconnection technologies if the passivation opening and spacing are adjusted in such a way that the progression is not modified.

1.4 The values stated in SI units are to be regarded as the standard. The values given in parentheses are for information only.

## 2. Terminology

### 2.1 Definitions:

2.1.1 *corner offset*—The orthogonal distance between the corner passivation opening on adjacent sides of the die where a corner passivation opening is identified as the end passivation opening on a die side.

2.1.2 *lead count*—The number of passivation openings available on a fully populated die layout.

2.1.3 *minimum die edge guard*—The minimum distance between the die edge and the passivation opening nearest to the die edge herein used to establish the minimum die size.

2.1.4 *minimum die size*—The minimum die size is calculated by the following equation:

$$\begin{aligned} \text{minimum die size} = & ((\text{lead count}/4) (\text{p.o. size} + \text{p.o. space})) \\ & - \text{p.o. space} + (2 (\text{corner offset} + \text{p.o. size} \\ & + \text{die edge guard})) \end{aligned}$$

2.1.5 *passivation opening*—The unpassivated area within the device metal bonding pad area.

2.1.6 *passivation opening size*—The minimum orthogonal dimensions of the passivation opening for the particular technology herein used as the nominal passivation opening size.

2.1.7 *passivation opening space*—The minimum space between adjacent passivation openings for the particular technology herein used as the nominal passivation opening spacing.

2.1.8 *progression*—The dimension as measured from a reference point on one passivation opening to the same reference point on the adjacent passivation opening.

2.1.9 *technology*—The minimum passivation opening progression allowable for a specific interconnection method.

## 3. Classification

3.1 The passivation opening layouts are separated into four technology types where:

Type I = 220  $\mu\text{m}$  technology (220  $\mu\text{m}$  = 8.7 mils)

Type II = 185  $\mu\text{m}$  technology (185  $\mu\text{m}$  = 7.3 mils)

Type III = 150  $\mu\text{m}$  technology (150  $\mu\text{m}$  = 5.9 mils)

Type IV = 100  $\mu\text{m}$  technology (100  $\mu\text{m}$  = 3.9 mils)

## 4. Dimensions, Mass, and Permissible Variations

4.1 The primary unit of measure is micrometres ( $\mu\text{m}$ ) (1 micrometre = 1 micron) and the secondary unit of measure is mils (1/1000 of an in.), where 1 mil (0.001 in.) = 25.4  $\mu\text{m}$ .

4.2 Fig. 1 shows the generic dimension measurement for each defined dimension.

4.3 The lead count independent dimensions are summarized in Table 1 for all technologies.

4.4 The specific standard layouts are listed in Tables 2-5 for Type I, Type II, Type III and Type IV technologies respectively.

4.5 *Progression*—Any variations must be noncumulative.

4.6 *Lead Count*—All passivation openings as specified in this specification must be included in the design whether they are or are not connected internally.

## 5. Keywords

5.1 opening layouts; passivation; semiconductor devices

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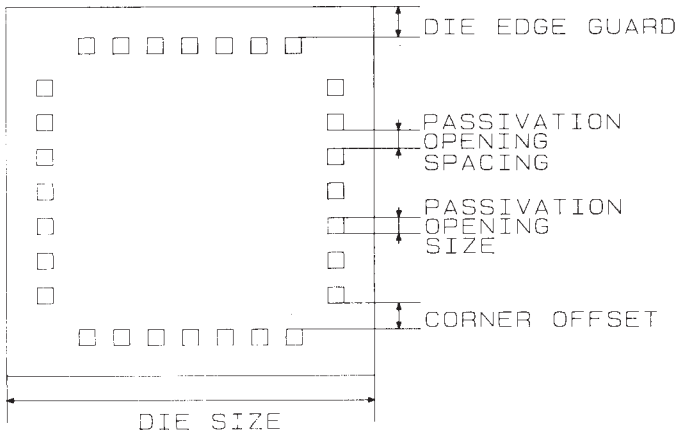


FIG. 1 Generic Dimension Measurement

TABLE 3 Specific Dimensions for the Type II (185 µm) Technology for Each Lead Count

Lead Count n	Passivation Opening Size, µm (mil)	Passivation Opening Space, µm (mil)	Corner Offset, µm (mil)	Minimum Die Edge Guard, µm (mil)	Minimum Die Size, µm (mil)
28	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	2.0 (78)
32	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	2.2 (86)
40	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	2.6 (100)
44	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	2.8 (107)
68	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	3.9 (151)
84	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	4.6 (180)
100	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	5.4 (209)
132	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	6.8 (268)
144	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	7.4 (290)
164	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	8.3 (326)
180	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	9.1 (355)
196	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	9.7 (384)
220	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	10.9 (428)
244	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	12.0 (472)
260	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)	12.8 (501)

TABLE 1 Generic Dimensions for the Various Technologies

Technology, µm (mil)	Passivation Opening Size, µm (mil)	Passivation Opening Space, µm (mil)	Corner Offset, µm (mil)	Die Edge Guard, µm (mil)
220 (8.7)	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)
185 (7.3)	80 (3.14)	105 (4.13)	188 (7.40)	125 (4.92)
150 (5.9)	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)
100 (3.9)	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)

TABLE 2 Specific Dimensions for the Type I (220 µm) Technology for Each Lead Count

Lead Count n	Passivation Opening Size, µm (mil)	Passivation Opening Space, µm (mil)	Corner Offset, µm (mil)	Minimum Die Edge Guard, µm (mil)	Minimum Die Size, µm (mil)
28	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	2.1 (81)
32	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	2.3 (90)
40	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	2.8 (107)
44	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	3.0 (116)
68	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	4.3 (168)
84	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	5.2 (202)
100	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	6.1 (237)
132	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	7.8 (306)
144	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	8.5 (332)
164	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	9.6 (375)
180	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	10.5 (410)
196	100 (3.94)	120 (4.72)	82 (3.23)	131 (5.16)	11.3 (444)

TABLE 4 Specific Dimensions for the Type III (150 µm) Technology for Each Lead Count

Lead Count n	Passivation Opening Size, µm (mil)	Passivation Opening Space, µm (mil)	Corner Offset, µm (mil)	Minimum Die Edge Guard, µm (mil)	Minimum die Size, µm (mil)
28	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	1.6 (62)
32	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	1.8 (68)
40	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	2.1 (79)
44	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	2.2 (85)
68	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	3.1 (121)
84	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	3.7 (144)
100	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	4.3 (168)
132	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	5.5 (215)
144	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	6.0 (233)
164	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	6.7 (262)
180	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	7.3 (286)
196	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	7.9 (310)
220	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	8.8 (345)
244	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	9.7 (381)
260	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	10.3 (404)
284	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	11.2 (440)
300	70 (2.76)	80 (3.14)	112 (4.41)	110 (4.33)	11.8 (463)



**TABLE 5 Specific Dimensions for the Type IV (100  $\mu\text{m}$ )  
Technology for Each Lead Count**

Lead Count n	Passivation Opening Size, $\mu\text{m}$ (mil)	Passivation Opening Space, $\mu\text{m}$ (mil)	Corner Offset, $\mu\text{m}$ (mil)	Minimum Die Edge Guard, $\mu\text{m}$ (mil)	Minimum Die Size, $\mu\text{m}$ (mil)
68	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	2.2 (83)
84	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	2.6 (99)
100	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	3.0 (115)
132	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	3.8 (146)
144	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	4.1 (158)
164	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	4.6 (178)
180	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	5.0 (194)
196	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	5.4 (209)
220	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	6.0 (233)
244	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	6.6 (257)
260	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	6.9 (272)
284	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	7.6 (296)
300	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	8.0 (312)
324	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	8.6 (335)
364	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	9.6 (375)
372	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	9.8 (383)
388	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	10.2 (398)
404	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	10.6 (414)
420	40 (1.57)	60 (2.36)	82 (3.23)	110 (4.33)	11.0 (430)

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